# 2SC4308

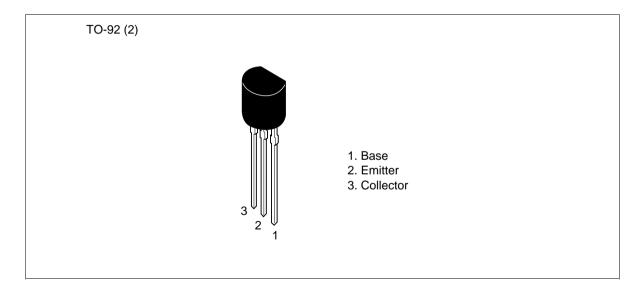
## Silicon NPN Epitaxial Planar

# **HITACHI**

#### **Application**

VHF Wide band amplifier

#### Outline





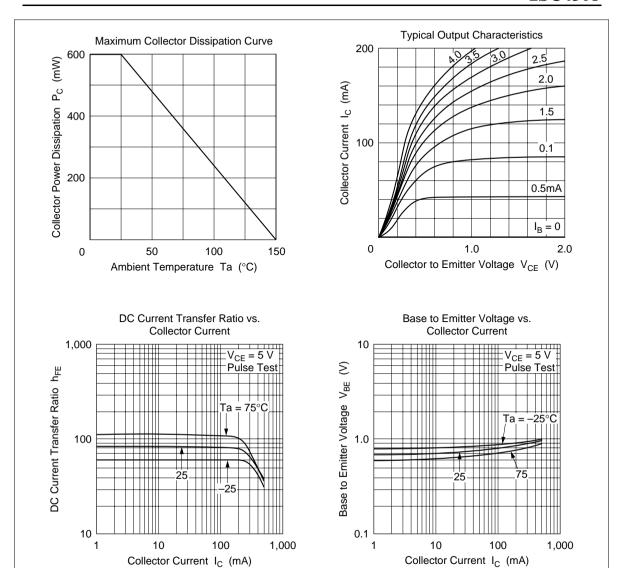
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### **Absolute Maximum Ratings** (Ta = 25°C)

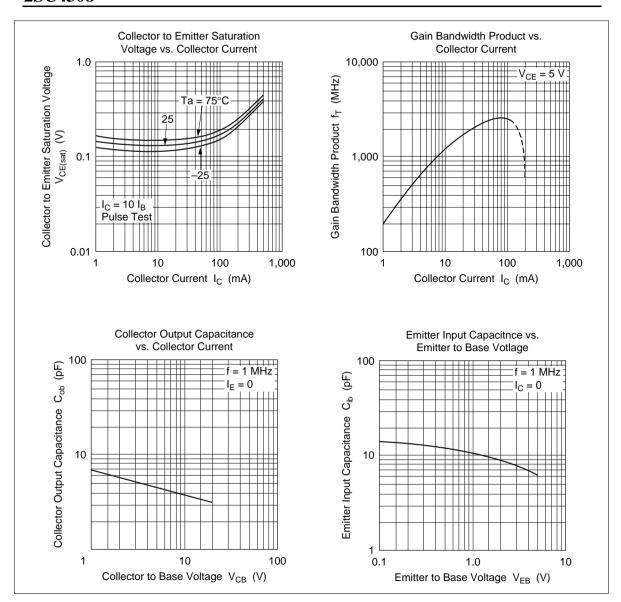
Item	Symbol	Ratings	Unit
Collector to base voltage	$V_{\text{CBO}}$	30	V
Collector to emitter voltage	V <sub>CEO</sub>	20	V
Emitter to base voltage	$V_{EBO}$	3	V
Collector current	I <sub>c</sub>	300	mA
Collector peak current	i <sub>C (peak)</sub>	500	mA
Collector power dissipation	P <sub>c</sub>	600	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

### **Electrical Characteristics** ( $Ta = 25^{\circ}C$ )

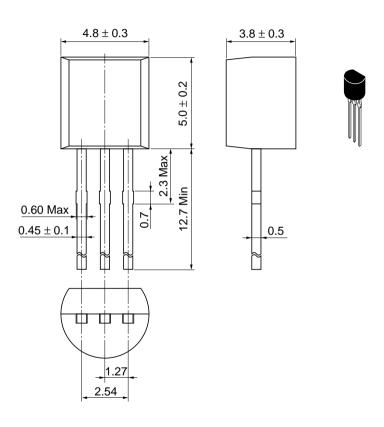
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{\text{(BR)CBO}}$	30	_	_	V	$I_{c} = 100 \ \mu\text{A}, \ I_{E} = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	20	_	_	V	$I_{C} = 1 \text{ mA}, R_{BE} = \infty$
Collector cutoff current	I <sub>CBO</sub>	_	_	1	μΑ	V <sub>CB</sub> = 25 V, I <sub>E</sub> = 0
Emitter cutoff current	I <sub>EBO</sub>	_	_	10	μΑ	$V_{EB} = 3 \text{ V}, I_{E} = 0$
DC current transfer ratio	h <sub>FE</sub>	50	_	200		$V_{CE} = 5 \text{ V}, I_{C} = 50 \text{ mA}$
Gain bandwidth product	f <sub>T</sub>	1.5	2.5	_	GHz	$V_{CE} = 5 \text{ V}, I_{C} = 50 \text{ mA}$
Collector output capacitance	Cob	_	4.0	_	pF	$V_{CB} = 10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$



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Unit: mm



Hitachi Code	TO-92 (2)
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.25 g

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